500 mW DO-35 Hermetically **Sealed Glass Zener Voltage Regulators**

This is a complete series of 500 mW Zener diodes with limits and excellent operating characteristics that reflect the superior capabilities of silicon-oxide passivated junctions. All this in an axial-lead hermetically sealed glass package that offers protection in all common environmental conditions.

Specification Features:

- Zener Voltage Range 2.4 V to 33 V
- ESD Rating of Class 3 (>16 KV) per Human Body Model
- DO-204AH (DO-35) Package Smaller than Conventional DO-204AA Package
- Double Slug Type Construction
- Metallurgical Bonded Construction

Mechanical Characteristics:

CASE: Double slug type, hermetically sealed glass FINISH: All external surfaces are corrosion resistant and leads are readily solderable

MAXIMUM LEAD TEMPERATURE FOR SOLDERING PURPOSES: 230°C, 1/16" from the case for 10 seconds POLARITY: Cathode indicated by polarity band MOUNTING POSITION: Any MAXIMUM RATINGS (Note 1)

MAXIMUM RATINGS (Note 1)

Rating	Symbol	Value	Unit
Max. Steady State Power Dissipation @ T _L ≤ 75°C, Lead Length = 3/8″ Derate above 75°C	PD	500 4.0	mW mW/°C
Operating and Storage Temperature Range	T _J , T _{stg}	-65 to +200	°C

ERA

1. Some part number series have lower JEDEC registered ratings.



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ORDERING INFORMATION

Device	Package	Shipping			
BZX55CxxxRL	Axial Lead	5000/Tape & Reel			
BZX55CxxxRL2*	Axial Lead	5000/Tape & Reel			

* The "2" suffix refers to 26 mm tape spacing.

ELECTRICAL CHARACTERISTICS (T_L = 30°C unless otherwise noted, $V_F = 1.5 \text{ V Max} @ I_F = 100 \text{ mA for all types}$)

Symbol	Parameter
VZ	Reverse Zener Voltage @ I _{ZT}
I _{ZT}	Reverse Current
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}
ΘV_{BR}	Temperature Coefficient of V _{BR} (Typical)
I _R	Reverse Leakage Current (T _A = 25°C) @ V_R
V _R	Breakdown Voltage
١ _F	Forward Current
V _F	Forward Voltage @ I _F
С	Capacitance (Typical)



ELECTRICAL CHARACTERISTICS (7)	30°C unless otherwise noted, V _F = 1.3 V Max, I _F = 100 m	Adc for all types)
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		V _{ZT} at I _{ZT} (V)		Max Zener		Max Reverse Leakage Current I _R at V _R (μA)			
Device	Device Marking	Min (Note 2)	Max (Note 2)	(Note 4) Z _{ZT} @ I _{ZT} (Ohms) Max	I _{ZT} (mA)	T _{amb} 25°C Max	T _{amb} 125°C Max	V _R (V)	<mark>I_{ZM} (mA)</mark> (Note 3)
BZX55C2V4RL	55C2V4	2.28	2.56	85	5	50	100	1	155
BZX55C2V7RL	55C2V7	2.5	2.9	85	5	10	50	1	135
BZX55C3V0RL	55C3V0	2.8	3.2	85	5	4	40	1	125
BZX55C3V3RL	55C3V3	3.1	3.5	85	5	2	40	1	115
BZX55C3V6RL	55C3V6	3.4	3.8	85	5	2	40	1	105
BZX55C3V9RL	55C3V9	3.7	4.1	85	5	2	40	1	95
BZX55C4V3RL	55C4V3	4	4.6	75	5	1	20	1	90
BZX55C4V7RL	55C4V7	4.4	5	60	5	0.5	10	1	85
BZX55C5V1RL	55C5V1	4.8	5.4	35	5	0.1	2	1	80
BZX55C5V6RL	55C5V6	5.2	6	25	5	0.1	2	1	70
BZX55C6V2RL	55C6V2	5.8	6.6	10	5	0.1	2	2	64
BZX55C6V8RL	55C6V8	6.4	7.2	8	5	0.1	2	3	58
BZX55C7V5RL	55C7V5		7.9	1	5	0.1	2	5	53
BZX55C8V2RL	55C8V2	7.7	8.7	7	5	0.1	2	6	47
BZX55C9V1RL	550901	8.5	9.6	10	5	0.1	2	1	43
BZX55C10RL	55C10	9.4	10.6	15	5	0.1	2	7.5	40
BZX55C11RL	55C11	10.4	11.6	20	5	0.1	2	8.5	36
BZX55C12RL	55C12	11.4	12.7	20	5	0.1	2	9	32
BZX55C13RL	55C13	12.4	14.1	26	5	0.1	2	10	29
BZX55C15RL	55C15	13.8	15.6	30	5	0.1	2	11	27
BZX55C16RL	55C16	15.3	17.1	40	5	0.1	2	12	24
BZX55C18RL	55C18	16.8	19.1	50	5	0.1	2	14	21
BZX55C20RL	55C20	18.8	21.1	55	5	0.1	2	15	20
BZX55C22RL	55C22	20.8	23.3	55	5	0.1	2	17	18
BZX55C24RL	55C24	22.8	25.6	80	5	0.1	2	18	16
BZX55C27RL	55C27	25.1	28.9	80	5	0.1	2	20	14
BZX55C30RL	55C30	28	32	80	5	0.1	2	22	13
BZX55C33RL	55C33	31	35	80	5	0.1	2	24	12
BZX55C36RL	55C36	34	38	80	5	0.1	2	27	11
BZX55C39RL	55C39	37	41	90	2.5	0.1	5	28	10
BZX55C43RL	55C43	40	46	90	2.5	0.1	5	32	9.2
BZX55C47RL	55C47	44	50	110	2.5	0.1	5	35	8.5
BZX55C51RL	55C51	48	54	125	2.5	0.1	10	38	7.8
BZX55C56RL	55C56	52	60	135	2.5	0.1	10	42	7
BZX55C62RL	55C62	58	66	150	2.5	0.1	10	47	6.4
BZX55C68RL	55C68	64	72	160	2.5	0.1	10	51	5.9
BZX55C75RL	55C75	70	80	170	2.5	0.1	10	56	5.3
BZX55C82RL	55C82	77	87	200	2.5	0.1	10	62	4.8
BZX55C91RL	55C91	85	96	250	1	0.1	10	69	4.3

2. TOLERANCE AND VOLTAGE DESIGNATION

Tolerance designation – the type numbers listed have zener voltage min/max limits as shown. Device tolerance of $\pm 2\%$ are indicated by a "B" instead of a "C". Zener voltage is measured with the device junction in thermal equilibrium at the lead temperature of $30^{\circ}C \pm 1^{\circ}C$ and 3/8''lead length.

3. This data was calculated using nominal voltages. The maximum current handling capability on a worst case basis is limited by the actual zener voltage at the operating point and the powered derating curve.
4. Z_{ZT} and Z_{ZK} are measured by dividing the ac voltage drop across the device by the ac current applied. The specified limits are for I_{Z(ac)} = 0.1 I_{Z(dc)} with the ac frequency = 1.0 kHz.



APPLICATION NOTE — ZENER VOLTAGE

Since the actual voltage available from a given zener diode is temperature dependent, it is necessary to determine junction temperature under any set of operating conditions in order to calculate its value. The following procedure is recommended:

Lead Temperature, T_L, should be determined from:

$$\mathsf{T}_{\mathsf{L}} = \theta_{\mathsf{L}\mathsf{A}}\mathsf{P}_{\mathsf{D}} + \mathsf{T}_{\mathsf{A}}.$$

 θ_{LA} is the lead-to-ambient thermal resistance (°C/W) and P_D is the power dissipation. The value for θ_{LA} will vary and depends on the device mounting method. θ_{LA} is generally 30 to 40°C/W for the various clips and tie points in common use and for printed circuit board wiring.

The temperature of the lead can also be measured using a thermocouple placed on the lead as close as possible to the tie point. The thermal mass connected to the tie point is normally large enough so that it will not significantly respond to heat surges generated in the diode as a result of pulsed operation once steady-state conditions are achieved. Using the measured value of T_{L} , the junction temperature may be determined by:

$$T_J = T_L + \Delta T_{JL}$$

 ΔT_{JL} is the increase in junction temperature above the lead temperature and may be found from Figure 2 for dc power:

$$\Delta T_{JL} = \theta_{JL} P_{D}.$$

For worst-case design, using expected limits of I_{Z_2} limits of P_D and the extremes of $T_J(\Delta T_J)$ may be estimated. Changes in voltage, V_Z, can then be found from:

$$\Delta \mathsf{V} = \theta_{\mathsf{VZ}}\mathsf{T}_{\mathsf{J}}.$$

 θ_{VZ} , the zener voltage temperature coefficient, is found from Figures 4 and 5.

Under high power-pulse operation, the zener voltage will vary with time and may also be affected significantly by the zener resistance. For best regulation, keep current excursions as low as possible.

Surge limitations are given in Figure 7. They are lower than would be expected by considering only junction temperature, as current crowding effects cause temperatures to be extremely high in small spots, resulting in device degradation should the limits of Figure 7 be exceeded.





Figure 3. Typical Leakage Current







Figure 9. Effect of Zener Voltage on Zener Impedance

Figure 10. Typical Forward Characteristics



Figure 12. Zener Voltage versus Zener Current — V_Z = 15 thru 30 Volts





OUTLINE DIMENSIONS

Zener Voltage Regulators – Axial Leaded

500 mW DO-35 Glass



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